TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP130

Programmable Controllers AC / DC-Input Module Telecommunication

The TOSHIBA mini flat coupler TLP130 is a small outline coupler, suitable for surface mount assembly.

TLP130 consists of a photo transistor, optically coupled to two gallium arsenide infrared emitting diodes connected inverse parallel, and operate directly by AC input current.

• Collector-emitter voltage: 80 V (min)

• Current transfer ratio: 50 % (min)
Rank GB: 100 % (min)

• Isolation voltage: 3750 Vrms (min)

• UL recognized: UL1577, file no. E67349

• Current transfer ratio

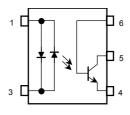
	Unit:	mm
6 5 4 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7	± 0.4	
	1	1-402
TOSHIBA 11-4C2	2	

Weight: 0.09 g (typ.)

	Current Transf	er Ratio (%) (I _C /I _F)		
Classification	I _F = 5mA, V _{CE}	Marking of Classification		
	Min Max			
Standard	50	600	Blank, GB	
Rank GB	100	600	GB	<

(Note) Application type name for certification test, please use standard product type name, i.e. TLP130(GB): TLP130

Pin Configurations (top view)



- 1 : Anode, Cathode
- 3 : Cathode, Anode
- 4 : Emitter
- 5 : Collector
- 6 · Rase



Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	I _{F(RMS)}	50	mA
Ω	Forward current derating (Ta≥53°C)	ΔI _F / °C	-0.7	mA / °C
LED	Peak forward current (100µs pulse, 100pps)	I _{FP}	1 📐	Α
	Junction temperature	Tj	125	°C
	Collector–emitter voltage	V _{CEO}	80) v
	Collector-base voltage	V _{CBO}	80	\
	Emitter-collector voltage	V _{ECO} <	7//	V
'n	Emitter-base voltage	V _{EBO}	7	V
Detector	Collector current	IC	50	mA
۵	Peak collector current (10ms pulse, 100 pps)	ICP	100	mA
	Power dissipation	PC	150	mW
	Power dissipation derating (Ta≥25°C)	ΔP _C /°C	-1.5	mW / °C
	Junction temperature	Ti	125	\c/\
Stor	age temperature range	T _{stg}	-55~125	\
Ope	rating temperature range	T _{opr}	-55~100	°C
Lea	d soldering temperature (10s)	T _{sol}	260	°C
Tota	al package power dissipation	PT	200	mW
Tota	al package power dissipation derating (Ta≥25°C)	ΔΡτ/°C	-2.0	mW / °C
Isola	ation voltage (AC, 1minute, R.H. ≤ 60%) (Note 1)	BVS	3750	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

(Note 1) Device considered a two terminal device: Pins 1 and 3 shorted together and pins 4, 5 and 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	VCC	_	5	48	٧
Forward current	I _{F(RMS)}	_	16	25	mA
Collector current	(le)	_	1	10	mA
Operating temperature	T _{opr}	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

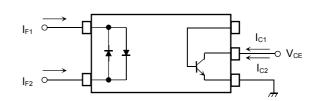
Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
LED	Forward voltage	V _F	I _F = ±10mA	1.0	1.15	1.3	V
۳	Capacitance	C _T	V = 0, f = 1MHz	_	60	_	pF
	Collector–emitter breakdown voltage	V _{(BR)CEO}	I _C = 0.5mA	80	7	1	V
	Emitter–collector breakdown voltage	V _{(BR)ECO}	I _E = 0.1mA	7			V
	Collector-base breakdown voltage	V _{(BR)CBO}	I _C = 0.1mA	80) } }		V
	Emitter-base breakdown voltage	V _{(BR)EBO}	I _E = 0.1mA	7	<i>)</i> }	1	V
Detector	Collector dark current	lana	V _{CE} = 48V		10	100	nA
Det	Collector dark current	ICEO	V _{CE} = 48V, Ta = 85°C	<u>)</u>	2	50	μΑ
	Collector dark current	ICER	V _{CE} = 48V, Ta = 85°C R _{BE} = 1MΩ)	0.5	10	μA
	Collector dark current	I _{CBO}	V _{CB} = 10V	_	0.1	/	nA
	DC forward current gain	h _{FE}	V _{CE} = 5V, I _C = 0.5mA	\Diamond	400))	
	Capacitance collector to emitter	C _{CE}	V = 0 , f = 1MHz	_	10	~(J)	pF

Coupled Electrical Characteristics (Ta = 25°C)

				$\overline{}$		
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	I _C / I _F	$I_F = \pm 5$ mA, $V_{CE} = 5$ V	50	_	600	%
Current transfer fatto	1071	Rank GB) 100	ı	600	70
Saturated CTR	I _C /I _{F(sat)}	$I_F = \pm 1 \text{mA}, V_{CE} = 0.4 \text{V}$	/	60	1	%
Saturated CTA	TC/TF(sat)	Rank GB	30	ı	1	70
Base photo-current	1 _{PB}	$I_F = \pm 5$ mA, $V_{CB} = 5$ V	1	10	1	μΑ
	77	$I_C = 2.4 \text{mA}, I_F = \pm 8 \text{mA}$	1	ı	0.4	
Collector-emitter saturation voltage	VCE(sat)	$I_C = 0.2 \text{mA}, I_F = \pm 1 \text{mA}$	_	0.2	_	V
Saturation voltage	7 <	Rank GB	_	_	0.4	
Off–state collector current	I _{C(off)}	$I_F = \pm 0.7 \text{mA}, V_{CE} = 48 \text{V}$	_	1	10	μΑ
CTR symmetry	I _{C(ratio)}	$I_C(I_F = -5mA) / I_C(I_F = 5mA)$ (Note 2)	0.33	_	3	

(Note 2) $I_{C(ratio)} = \frac{I_{C2}(I_F = I_{F2}, V_{CE} = 5V)}{I_{C1}(I_F = I_{F1}, V_{CE} = 5V)}$



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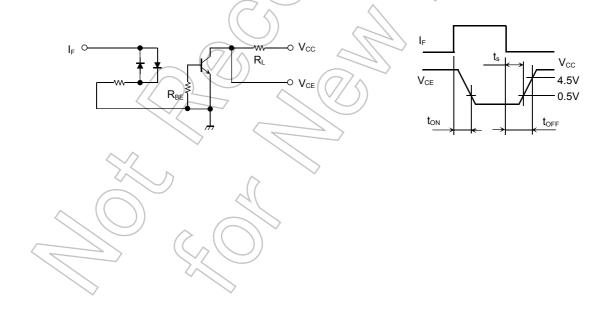
Isolation Characteristics (Ta = 25°C)

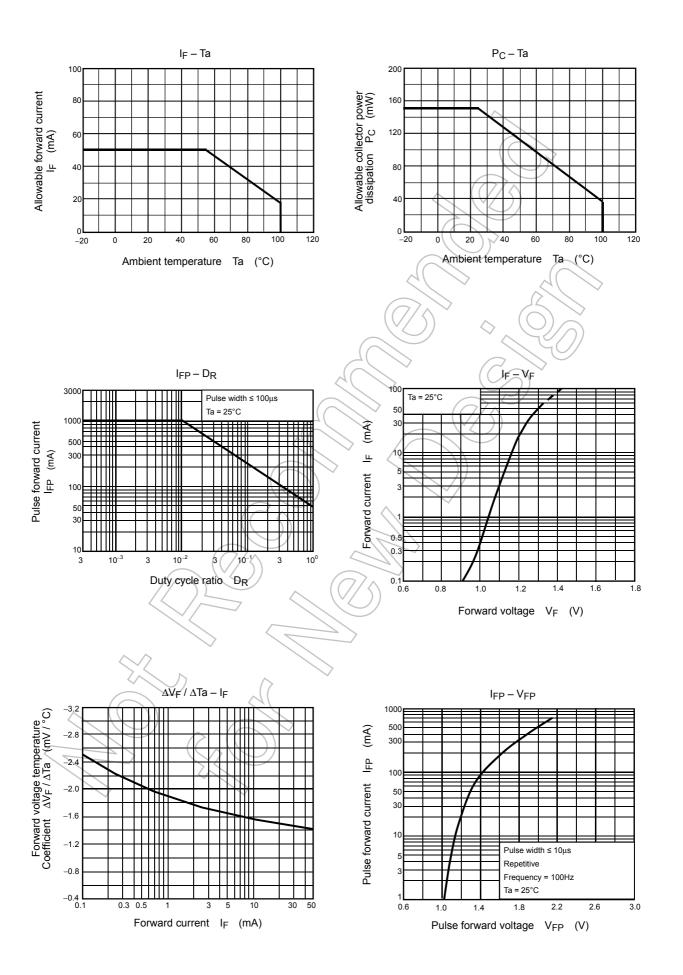
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	V _S = 0, f = 1MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500V	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage	BVS	AC, 1minute	3750	<u> </u>	_	\/ n.m. n
		AC, 1second, in oil	_	10000	_	Vrms
		DC, 1 minute, in oil	_	10000)/-	Vdc

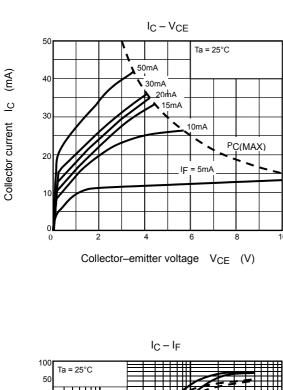
Switching Characteristics (Ta = 25°C)

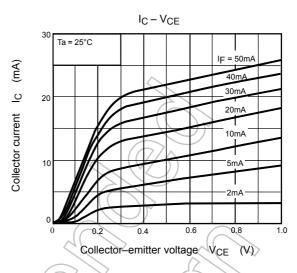
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	t _r			2		
Fall time	t _f	V _{CC} = 10V, I _C = 2mA	_	3	72.	
Turn-on time	t _{on}	$R_L = 100\Omega$	7 —	3	7-//	μs
Turn-off time	t _{off}		_<	3		
Turn-on time	t _{ON}	$R_L = 1.9 \text{ k}\Omega$ (Fig.1)	-	2		
Storage time	ts	R _{BE} = OPEN	-((25	_	μs
Turn-off time	toff	$V_{CC} = 5 \text{ V}, I_F = \pm 16 \text{mA}$		40	_	
Turn-on time	t _{ON}	$R_{L} = 1.9k\Omega$ (Fig.1)	$(\mathcal{A}/\mathcal{S})$	2	_	
Storage time	t _s	$R_{BF} = 220k\Omega$		20	_	μs
Turn-off time	toff	$V_{CC} = 5 \text{ V}, I_F = \pm 16 \text{mA}$	//-	30	_	

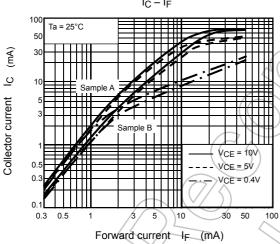
Fig. 1 Switching time test circuit

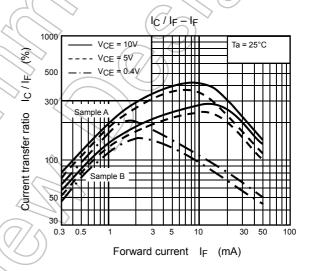


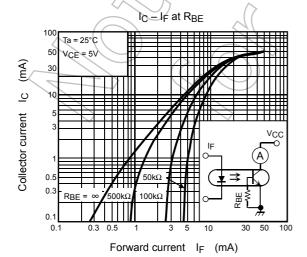


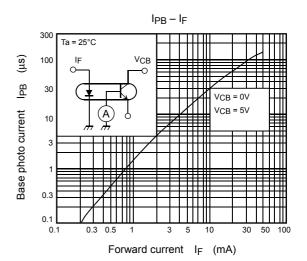




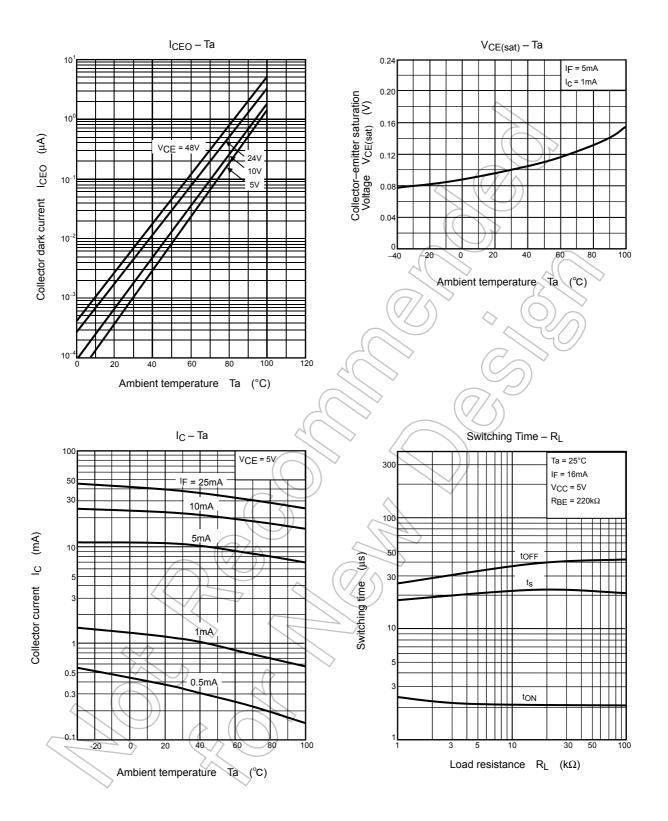




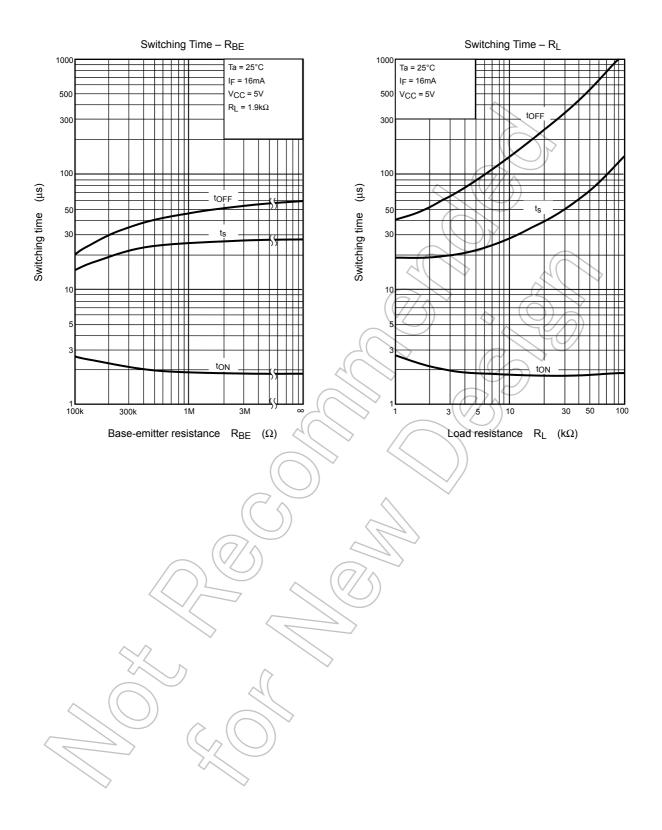




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